

Solid State Relay OCMOS FET

# PS7141C-2A, PS7141CL-2A

# 8-PIN DIP, 200 mA TYP. CURRENT LIMIT TYPE 2-ch Optical Coupled MOS FET

#### **DESCRIPTION**

The PS7141C-2A and PS7141CL-2A are solid state relays containing GaAs LEDs on the light emitting side (input side) and MOS FETs including current control circuit on the output side. Current control circuit of OCMOS FET protects this device from thermal breakdown and output circuit.

They are suitable for analog signal control because of their low offset and high linearity.

The PS7141CL-2A has a surface mount type lead.

#### **FEATURES**

- Limit current (ILMT = 170 to 250 mA)
- 2 channel type (1 a + 1 a output)
- Low LED operating current (IF = 2 mA)
- · Designed for AC/DC switching line changer
- Small package (8-pin DIP)
- · Low offset voltage
- PS7141CL-2A: Surface mount type

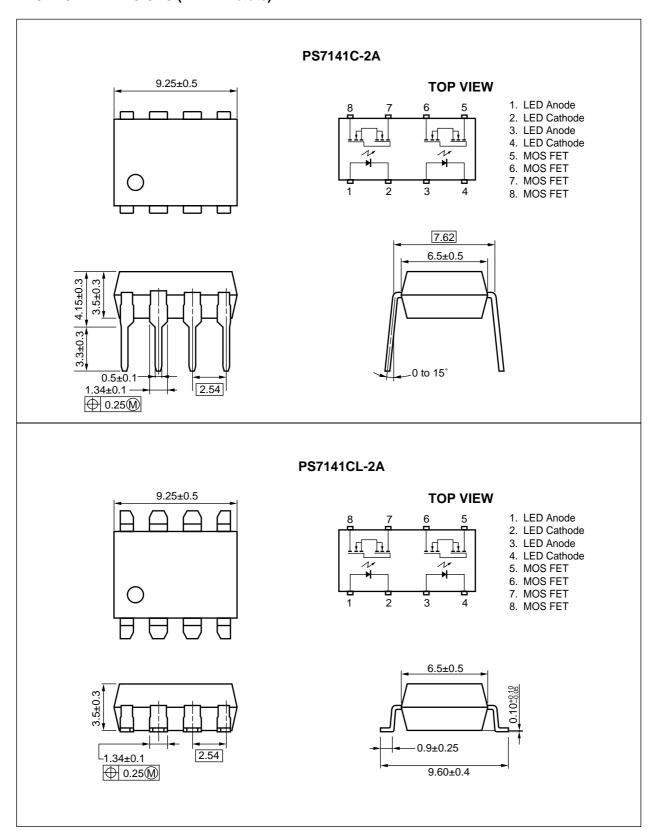
#### **APPLICATIONS**

- · Exchange equipment
- · Measurement equipment
- FA/OA equipment

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

### **PACKAGE DIMENSIONS (in millimeters)**



#### **★ ORDERING INFORMATION**

Part Number	Package	Packing Style	Application Part Number 1
PS7141C-2A	8-pin DIP	Magazine case 50 pcs	PS7141C-2A
PS7141CL-2A			PS7141CL-2A
PS7141CL-2A-E3		Embossed Tape 1 000 pcs/reel	
PS7141CL-2A-E4			

<sup>\*1</sup> For the application of the Safety Standard, following part number should be used.

### ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit	
Diode	Forward Current (DC)	lF	50	mA	
	Reverse Voltage	VR	5.0	V	
	Power Dissipation	PD	50	mW/ch	
	Peak Forward Current <sup>™</sup>	IFP	1	Α	
MOS FET	Break Down Voltage	VL	400	V	
	Continuous Load Current	lι	120	mA	
	Pulse Load Current <sup>2</sup> (AC/DC Connection)	Ігь	120	mA	
	Power Dissipation	Po	375	mW/ch	
Isolation Voltage*3		BV	1 500	Vr.m.s.	
Total Power Dissipation		Рт	850	mW	
Operating Ambient Temperature		TA	-40 to +80	°C	
Storage Temperature		T <sub>stg</sub>	-40 to +100	°C	

<sup>\*1</sup> PW = 100  $\mu$ s, Duty Cycle = 1 %

### RECOMMENDED OPERATING CONDITIONS (TA = 25 °C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
LED Operating Current	lF	2	10	20	mA
LED Off Voltage	VF	0		0.5	V

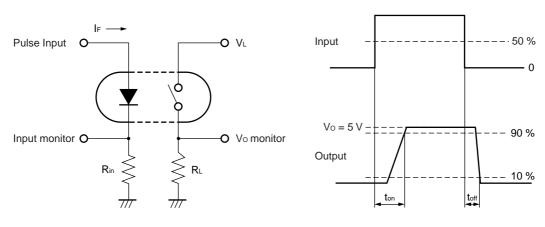
<sup>\*2</sup> PW = 100 ms, 1 shot

<sup>\*3</sup> AC voltage for 1 minute at  $T_A = 25$  °C, RH = 60 % between input and output

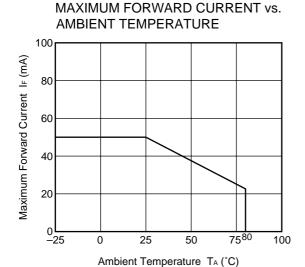
## ELECTRICAL CHARACTERISTICS (TA = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA		1.2	1.4	V
	Reverse Current	lR	V <sub>R</sub> = 5 V			5.0	μΑ
MOS FET	Off-state Leakage Current	Loff	V <sub>D</sub> = 400 V		0.03	1.0	μΑ
	Output Capacitance	Cout	V <sub>D</sub> = 0 V, f = 1 MHz		65		pF/ch
Coupled	LED On-state Current	IFon	IL = 120 mA			2.0	mA
	On-state Resistance	R <sub>on1</sub>	IF = 10 mA, IL = 10 mA		26	35	Ω
		Ron2	$I_F = 10 \text{ mA}, I_L = 120 \text{ mA}, t \le 10 \text{ ms}$		22	30	
	Turn-on Time <sup>*1</sup>	ton	I <sub>F</sub> = 10 mA, V <sub>O</sub> = 5 V, PW ≥ 10 ms		0.6	2.0	ms
	Turn-off Time <sup>*1</sup>	<b>t</b> off			0.03	1.0	
	Isolation Resistance	R <sub>I-O</sub>	Vi-o = 1.0 kVpc	10°			Ω
	Isolation Capacitance	C <sub>I-O</sub>	V = 0 V, f = 1 MHz		1.1		pF/ch
	Limit Current	Іьмт	IF = 10 mA, t = 5 ms, VL = 6 V	170	200	250	mA/ch

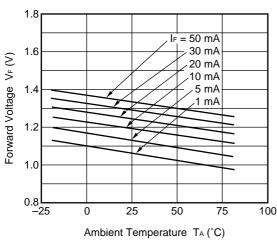
### \*1 Test Circuit for Switching Time



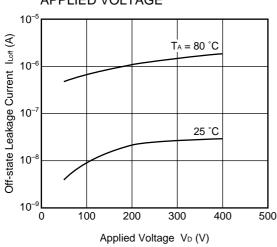
#### **★** TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)



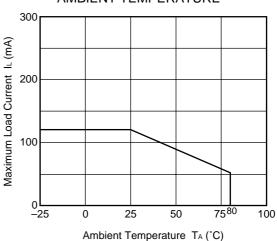




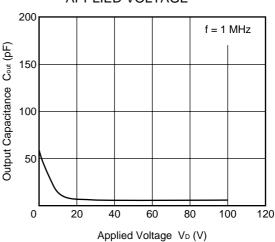
# OFF-STATE LEAKAGE CURRENT vs. APPLIED VOLTAGE



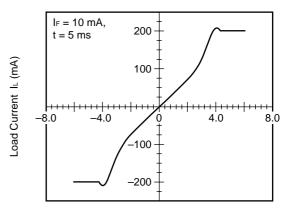
# MAXIMUM LOAD CURRENT vs. AMBIENT TEMPERATURE



# OUTPUT CAPACITANCE vs. APPLIED VOLTAGE

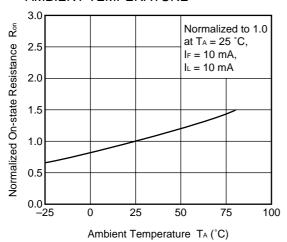


#### LOAD CURRENT vs. LOAD VOLTAGE

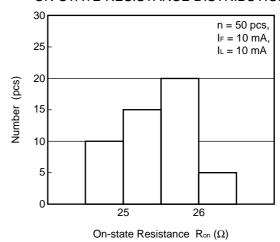


Load Voltage V<sub>L</sub> (V)

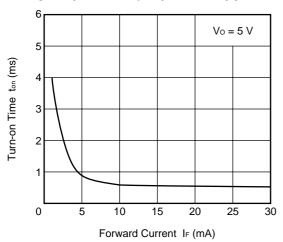
# NORMALIZED ON-STATE RESISTANCE vs. AMBIENT TEMPERATURE



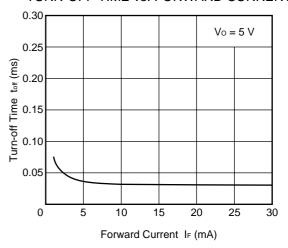
#### **ON-STATE RESISTANCE DISTRIBUTION**



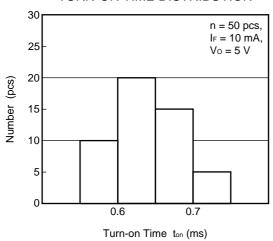
#### TURN-ON TIME vs. FORWARD CURRENT



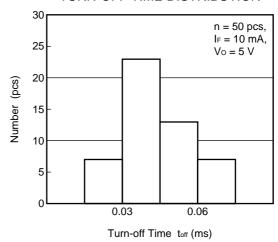
#### TURN-OFF TIME vs. FORWARD CURRENT



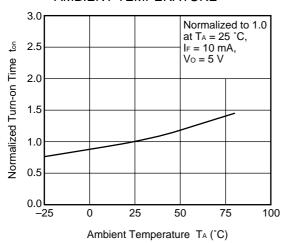
#### TURN-ON TIME DISTRIBUTION



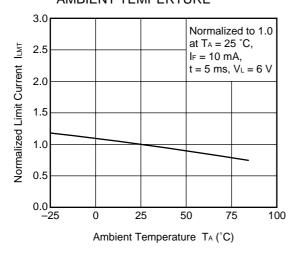
#### TURN-OFF TIME DISTRIBUTION



# NORMALIZED TURN-ON TIME vs. AMBIENT TEMPERATURE

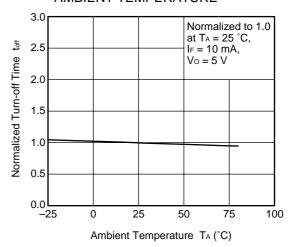


# NORMALIZED LIMIT CURRENT vs. AMBIENT TEMPERTURE

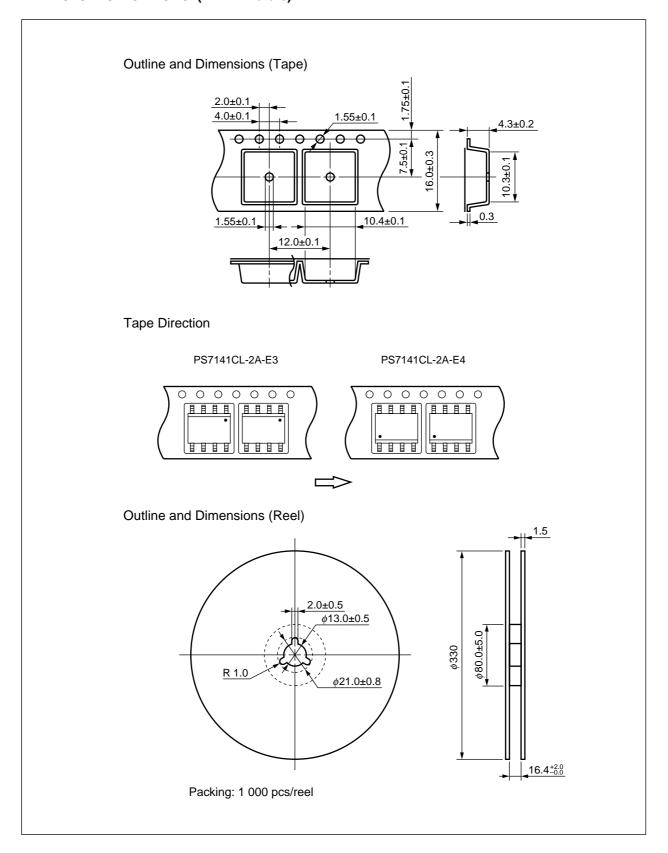


**Remark** The graphs indicate nominal characteristics.

# NORMALIZED TURN-OFF TIME vs. AMBIENT TEMPERATURE



### **★ TAPING SPECIFICATIONS (in millimeters)**



#### **★ RECOMMENDED SOLDERING CONDITIONS**

#### (1) Infrared reflow soldering

Peak reflow temperature
 235 °C (package surface temperature)

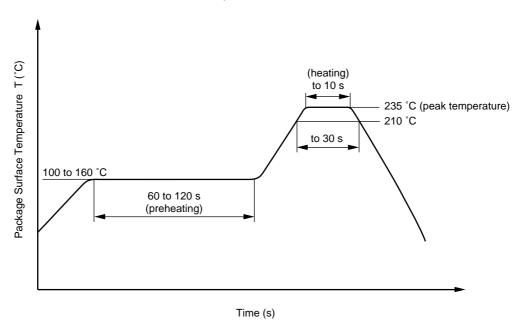
• Time of temperature higher than 210 °C 30 seconds or less

• Number of reflows Two

Flux
 Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt % is recommended.)

#### Recommended Temperature Profile of Infrared Reflow



### (2) Dip soldering

• Temperature 260 °C or below (molten solder temperature)

• Time 10 seconds or less

• Number of times One

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of

0.2 Wt % is recommended.)

### (3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

[MEMO]

[MEMO]

#### **CAUTION**

Within this device there exists GaAs (Gallium Arsenide) material which is a harmful substance if ingested. Please do not under any circumstances break the hermetic seal.

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